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# 74HC173; 74HCT173

Quad D-type flip-flop; positive-edge trigger; 3-state

Rev. 3 — 8 November 2016

Production

**Product data sheet** 

### General description

The 74HC173; 74HCT173 is a quad positive-edge triggered D-type flip-flop. The device features clock (CP), master reset (MR), two input enable (E1, E2) and two output enable (OE1, OE2) inputs. When the input enables are LOW, the outputs Qn will assume the state of their corresponding Dn inputs that meet the set-up and hold time requirements on the LOW-to-HIGH clock (CP) transition. A HIGH on either input enable will cause the device to go into a hold mode, outputs hold their previous state independently of clock and data inputs. A HIGH on MR forces the outputs LOW independently of clock and data inputs. A HIGH on either output enable pin causes the outputs to assume a high-impedance OFF-state. Operation of the output enable inputs does not affect the state of the flip-flops. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

#### **Features and benefits** 2.

- Complies with JEDEC standard no. 7A
- Input levels:
  - ◆ For 74HC173: CMOS level
  - For 74HCT173: TTL level
- Gated input enable for hold (do nothing) mode
- Gated output enable control mode
- Edge-triggered D-type register
- Asynchronous master reset
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

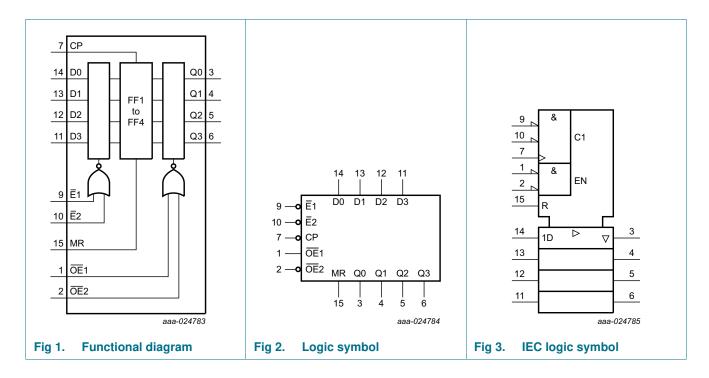


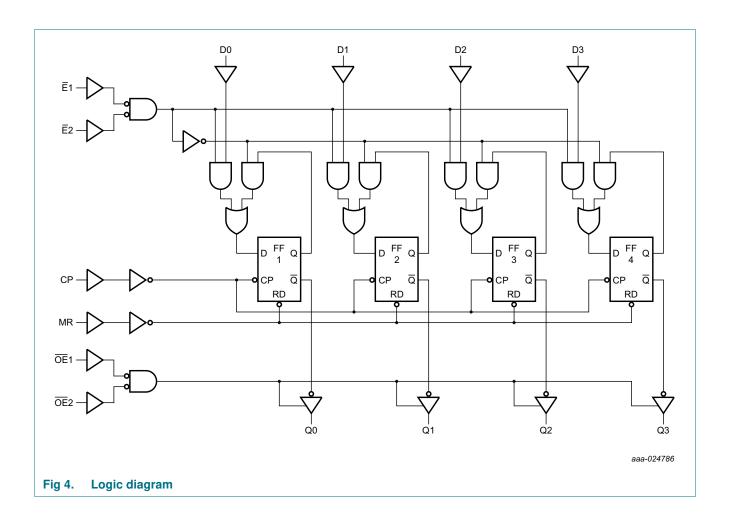
# 3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC173D	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1
74HCT173D			body width 3.9 mm	
74HC173DB	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1
74HCT173DB			body width 5.3 mm	
74HC173PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

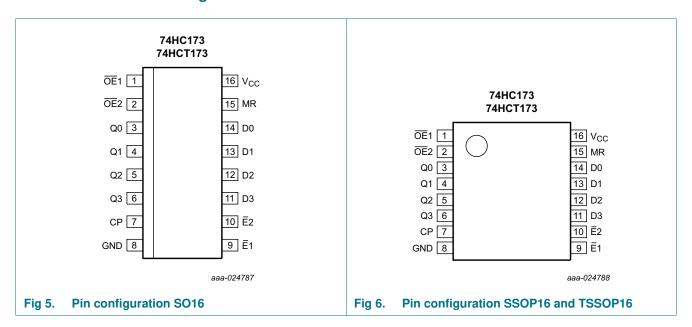
# 4. Functional diagram





# 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
OE1, OE2	1, 2	output enable input (active LOW)
Q0, Q1, Q2, Q3	3, 4, 5, 6	3-state flip-flop output
СР	7	clock input (LOW-to-HIGH, edge triggered)
GND	8	ground (0 V)
<u>E</u> 1, <u>E</u> 2	9, 10	data enable input (active LOW)
D0, D1, D2, D3	14, 13, 12, 11	data input
MR	15	asynchronous master reset (active HIGH)
V <sub>CC</sub>	16	supply voltage

# 6. Functional description

Table 3. Function table[1]

Register operating mode	Inputs		Outputs			
	MR	СР	CP         E1         E2         Dn           X         X         X         X		Qn (register)	
Reset (clear)	Н	Х	Х	Х	Х	L
Parallel load	L	1	I	I	I	L
	L	1	I	I	h	Н
Hold (do nothing)	L	Х	h	Х	Х	q <sub>n</sub>
	L	Х	Х	h	X	q <sub>n</sub>

Table 4. Function table[1]

3-state buffer operating mode	Inputs			Outpu	Outputs				
	Qn (register)	OE1	OE2	Q0	Q1	Q2	Q3		
Read	L	L	L	L	L	L	L		
	Н	L	L	Н	Н	Н	Н		
Disabled	X	Н	Х	Z	Z	Z	Z		
	X	Χ	Н	Z	Z	Z	Z		

<sup>[1]</sup> H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition;

# 7. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_1 < -0.5 \text{ V or } V_1 > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±35	mA
I <sub>CC</sub>	supply current			-	+70	mA
I <sub>GND</sub>	ground current			-70	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	SO16 and (T)SSOP16 package	<u>[1]</u>	-	500	mW

<sup>[1]</sup> For SO16 packages: above 70 °C the value of  $P_{tot}$  derates linearly at 8 mW/K. For (T)SSOP16 packages: above 60 °C the value of  $P_{tot}$  derates linearly at 5.5 mW/K.

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L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition;

q<sub>n</sub> = lower case letters indicate the state of the referenced input (or output) one set-up time prior to the LOW-to-HIGH CP transition;

X = don't care;

Z = high impedance OFF-state;

 $<sup>\</sup>uparrow$  = LOW-to-HIGH clock transition.

# 8. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC173			74HCT173			
			Min	Тур	Max	Min	Тур	Max		
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	٧	
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	٧	
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	٧	
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C	
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V	
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V	
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V	

### 9. Static characteristics

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC173	3		1	1		-	-			1
$V_{IH}$	HIGH-level	$V_{CC} = 2.0 \text{ V}$	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
$V_{IL}$	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.8	-	1.8	-	1.8	V
$V_{OH}$	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	٧
		$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	٧
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	٧
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	٧
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	٧
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	٧
		$I_O = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	٧
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 6.0$ V; $V_O = V_{CC}$ or GND	-	-	±0.5	-	±5.0	-	±10	μΑ

 Table 7.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8	-	80	-	160	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	73									
$V_{IH}$	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	٧
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -6.0 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 6.0 mA	-	0.16	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5 \text{ V}$ ; $V_O = V_{CC}$ or GND	-	-	±0.5	-	±5.0	-	±10	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $I_O = 0$ A	-	-	8.0	-	80	-	160	μΑ
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to $5.5 \text{ V}$ ; $I_O = 0 \text{ A}$								
		OE1, OE2	-	50	180	-	225	-	245	μΑ
		MR	-	60	216	-	270	-	294	μΑ
		<u>E</u> 1, <u>E</u> 2	-	40	144	-	180	-	196	μА
		Dn	-	25	90	-	112.5	-	122.5	μА
		CP	-	100	360	-	450	-	490	μА
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

# 10. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V);  $C_L$  = 50 pF unless otherwise specified; for test circuit see Figure 11.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC17	3									
t <sub>pd</sub>	propagation	CP to Qn; see Figure 7	1							
	delay	V <sub>CC</sub> = 2.0 V	-	55	175	-	220	-	265	ns
		V <sub>CC</sub> = 4.5 V	-	20	35	-	44	-	53	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	17	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	16	30	-	37	-	45	ns
t <sub>PHL</sub>	High to	MR to Qn; see Figure 8								
	LOW	V <sub>CC</sub> = 2.0 V	-	44	150	-	190	-	225	ns
	propagation delay	V <sub>CC</sub> = 4.5 V	-	16	30	-	38	-	45	ns
	•	V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	13	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	13	26	-	33	-	38	ns
t <sub>en</sub>	enable time	OEn to Qn; see Figure 9	1							
		V <sub>CC</sub> = 2.0 V	-	52	150	-	190	-	225	ns
		V <sub>CC</sub> = 4.5 V	-	19	30	-	38	-	45	ns
		V <sub>CC</sub> = 6.0 V	-	15	26	-	33	-	38	ns
t <sub>dis</sub>	disable time	OEn to Qn; see Figure 9	1							
		V <sub>CC</sub> = 2.0 V	-	52	150	-	190	-	225	ns
		V <sub>CC</sub> = 4.5 V	-	19	30	-	38	-	45	ns
		V <sub>CC</sub> = 6.0 V	-	15	26	-	33	-	38	ns
t <sub>t</sub>	transition	see Figure 7	1							
	time	V <sub>CC</sub> = 2.0 V	-	14	60	-	75	-	90	ns
		V <sub>CC</sub> = 4.5 V	-	5	12	-	15	-	18	ns
		V <sub>CC</sub> = 6.0 V	-	4	10	-	13	-	15	ns
t <sub>W</sub>	pulse width	CP HIGH or LOW; see Figure 7								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
		MR HIGH; see Figure 8								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
t <sub>rec</sub>	recovery	MR to CP; see Figure 8								
	time	V <sub>CC</sub> = 2.0 V	60	-8	-	75	-	90	-	ns
		V <sub>CC</sub> = 4.5 V	12	-3	-	15	-	18	-	ns
ı		V <sub>CC</sub> = 6.0 V	10	-2	-	13	-	15	-	ns

Table 8. **Dynamic characteristics** ...continued

Voltages are referenced to GND (ground = 0 V); C<sub>L</sub> = 50 pF unless otherwise specified; for test circuit see Figure 11.

Symbol	Parameter	Conditions			25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			ı	Min	Тур	Max	Min	Max	Min	Max	
t <sub>su</sub>	set-up time	En to CP; see Figure 10									
	·	V <sub>CC</sub> = 2.0 V		100	33	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V		20	12	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V		17	10	-	21	-	26	-	ns
		Dn to CP; see Figure 10									
		V <sub>CC</sub> = 2.0 V		60	17	-	75	-	90	-	ns
		V <sub>CC</sub> = 4.5 V		12	6	-	15	-	18	-	ns
		V <sub>CC</sub> = 6.0 V		10	5	-	13	-	15	-	ns
t <sub>h</sub>	hold time	En to CP; see Figure 10									
		V <sub>CC</sub> = 2.0 V		0	-17	-	0	-	0	-	ns
		V <sub>CC</sub> = 4.5 V		0	-6	-	0	-	0	-	ns
		V <sub>CC</sub> = 6.0 V		0	-5	-	0	-	0	-	ns
		Dn to CP; see Figure 10									
		V <sub>CC</sub> = 2.0 V		1	-11	-	1	-	1	-	ns
		V <sub>CC</sub> = 4.5 V		1	-4	-	1	-	1	-	ns
		V <sub>CC</sub> = 6.0 V		1	-3	-	1	-	1	-	ns
f <sub>max</sub>	maximum	CP; see Figure 7									
	frequency	V <sub>CC</sub> = 2.0 V		6	26	-	4.8	-	4	-	MHz
		V <sub>CC</sub> = 4.5 V		30	80	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	88	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V		35	95	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}; V_{CC} = 5 \text{ V};$ $f_i = 1 \text{ MHz}$	[5]	-	20	-	-	-	-	-	pF
74HCT1									1		
t <sub>pd</sub>	propagation	CP to Qn; see Figure 7	[1]								
Pu	delay	V <sub>CC</sub> = 4.5 V		-	20	40	-	50	-	60	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF		-	17	-	-	-	-	-	ns
t <sub>PHL</sub>	High to	MR to Qn; see Figure 8									
	LOW	V <sub>CC</sub> = 4.5 V		-	20	37	-	46	-	56	ns
	propagation delay	V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF		-	17	-	-	-	-	-	ns
t <sub>en</sub>	enable time		[2]	-	20	35	-	44	-	53	ns
t <sub>dis</sub>	disable time	<u> </u>	[3]	-	19	30	-	38	-	45	ns
t <sub>t</sub>	transition time	V <sub>CC</sub> = 4.5 V; see Figure 7	[4]	-	5	12	-	15	-	19	ns
t <sub>W</sub>	pulse width	CP HIGH or LOW; V <sub>CC</sub> = 4.5 V; see Figure 7		16	7	-	20	-	24	-	ns
		MR HIGH; V <sub>CC</sub> = 4.5 V; see <u>Figure 8</u>		15	6	-	19	-	22	-	ns

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 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); C<sub>L</sub> = 50 pF unless otherwise specified; for test circuit see Figure 11.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>rec</sub>	recovery time	MR to CP; V <sub>CC</sub> = 4.5 V; see Figure 8	12	-2	-	15	-	18	-	ns
t <sub>su</sub>	set-up time	En to CP; V <sub>CC</sub> = 4.5 V; see Figure 10	22	13	-	28	-	33	-	ns
		Dn to CP; V <sub>CC</sub> = 4.5 V; see <u>Figure 10</u>	12	7	-	15	-	18	-	ns
t <sub>h</sub>	hold time	En to CP; V <sub>CC</sub> = 4.5 V; see Figure 10	0	-6	-	0	-	0	-	ns
		Dn to CP; V <sub>CC</sub> = 4.5 V; see <u>Figure 10</u>	0	-3	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP; see Figure 7								
	frequency	V <sub>CC</sub> = 4.5 V	30	80	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	88	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC} - 1.5 \text{ V};$ $V_{CC} = 5 \text{ V}; f_{i} = 1 \text{ MHz}$	-	20	-	-	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .
- [2]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .
- [3]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .
- [4]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .
- [5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$$
 where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

### 11. Waveforms

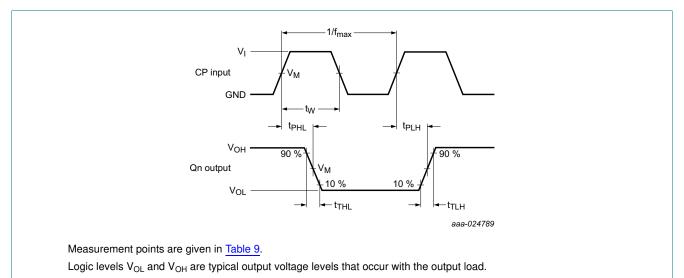
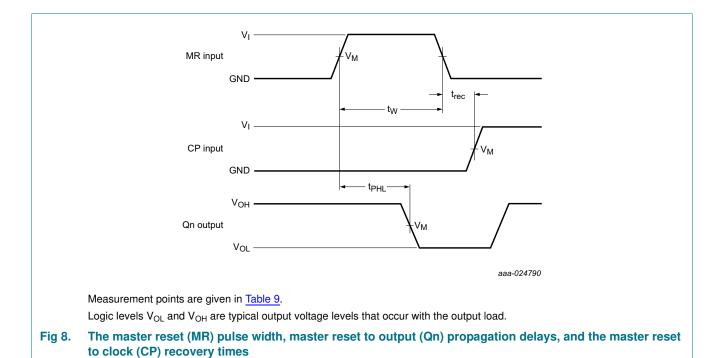
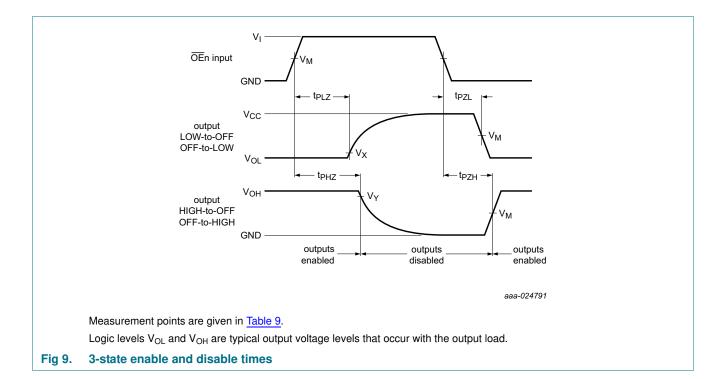
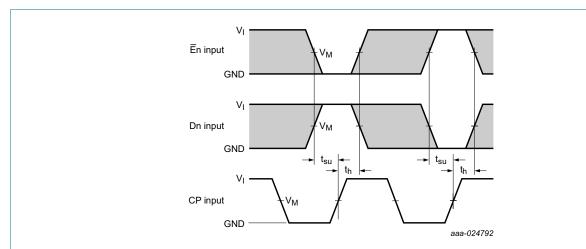


Fig 7. The clock (CP) to outputs (Qn) propagation delays, clock pulse width, output transition times and maximum frequency







The shaded areas indicate when the input is permitted to change for predictable output performance. Measurement points are given in <u>Table 9</u>.

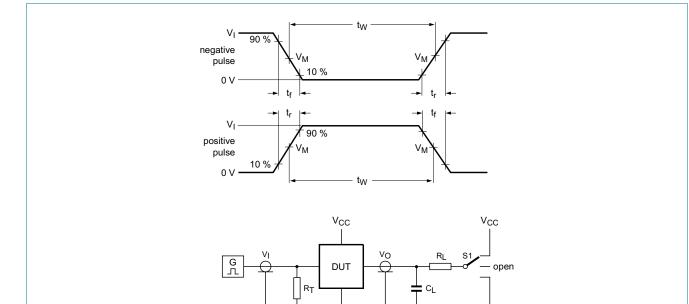
Fig 10. The data set-up and hold times from input (En, Dn) to clock (CP)

Table 9. Measurement points

Туре	Input	Output		
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
74HC173	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$
74HCT173	1.3 V	1.3 V	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$

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Test data is given in Table 10.

Test circuit definitions:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator

 $C_L$  = Load capacitance including jig and probe capacitance

R<sub>L</sub> = Load resistance.

S1 = Test selection switch

Fig 11. Test circuit for measuring switching times

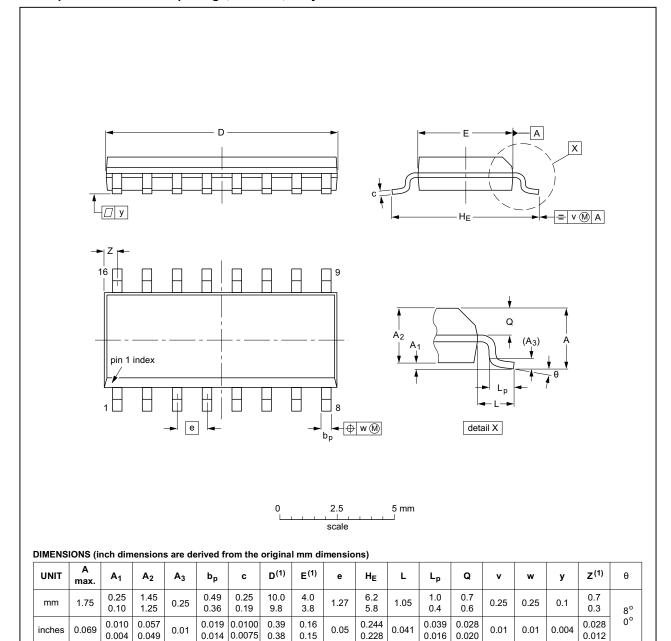
Table 10. Test data

Туре	Input		Load		S1 position			
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>	
74HC173	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>	
74HCT173	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>	

# 12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			<del>99-12-27</del> 03-02-19	

Fig 12. Package outline SOT109-1 (SO16)

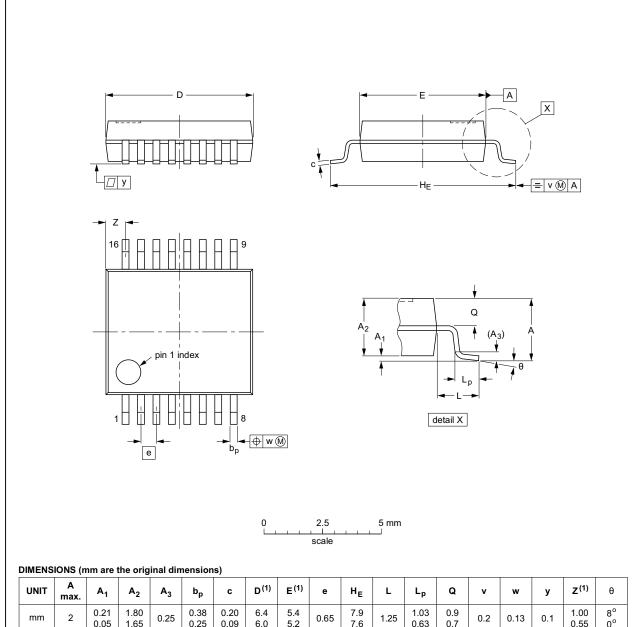
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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC JEITA		PROJECTION	ISSUE DATE	
SOT338-1		MO-150			<del>99-12-27</del> 03-02-19	

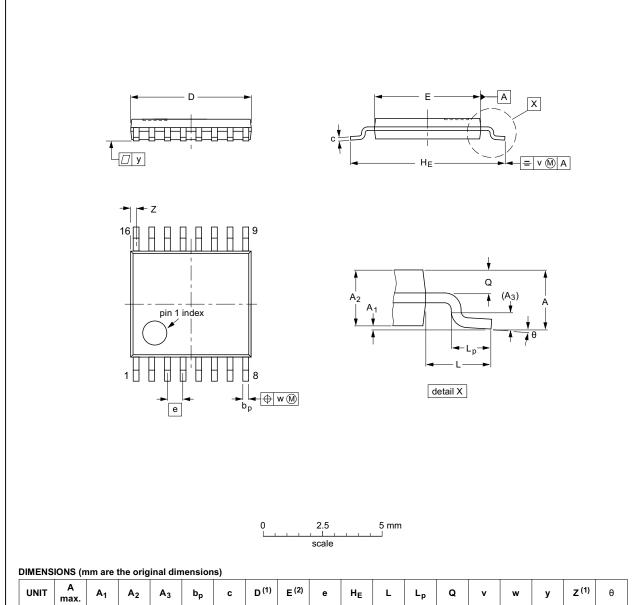
Fig 13. Package outline SOT338-1 (SSOP16)

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	REFER	EUROPEAN	ISSUE DATE			
IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
	MO-153				<del>99-12-27</del> 03-02-18	
	IEC	IEC JEDEC		IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION	

Fig 14. Package outline SOT403-1 (TSSOP16)

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## 13. Abbreviations

#### Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT173 v.3	20161108	Product data sheet	-	74HC_HCT173 v.2		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>					
	<ul> <li>Legal texts ha</li> </ul>	ive been adapted to the new c	ompany name wher	e appropriate.		
	Type numbers	s 74HCT173N and 74HC173N	removed.			
74HC_HCT173 v.2	19901201	Product specification	-	-		

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#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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# 74HC173; 74HCT173

#### Quad D-type flip-flop; positive-edge trigger; 3-state

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Quad D-type flip-flop; positive-edge trigger; 3-state

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